

74AUP1G17

Low-power Schmitt trigger

Rev. 14 — 18 July 2023

Product data sheet

1. General description

The 74AUP1G17 is a single buffer with Schmitt-trigger input. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 ° C to +85 ° C and -40 ° C to +125 ° C

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G17GW	-40 ° C to +125 ° C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G17GV	-40 ° C to +125 ° C	SC-74A	plastic surface-mounted package; 5 leads	SOT753
74AUP1G17GM	-40 ° C to +125 ° C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G17GN	-40 ° C to +125 ° C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G17GS	-40 ° C to +125 ° C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G17GX	-40 ° C to +125 ° C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3
74AUP1G17GX4	-40 ° C to +125 ° C	X2SON4	plastic thermal enhanced extremely thin small outline package; no leads; 4 terminals; body 0.6 × 0.6 × 0.32 mm	SOT1269-2

4. Marking

Table 2. Marking

Type number	Marking code[1]
74AUP1G17GW	pJ
74AUP1G17GV	pJ
74AUP1G17GM	pJ
74AUP1G17GN	pJ
74AUP1G17GS	pJ
74AUP1G17GX	pJ
74AUP1G17GX4	pJ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

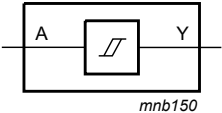


Fig. 1. Logic symbol

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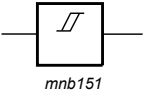


Fig. 2. IEC logic symbol

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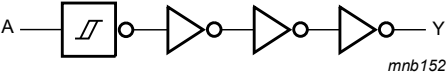
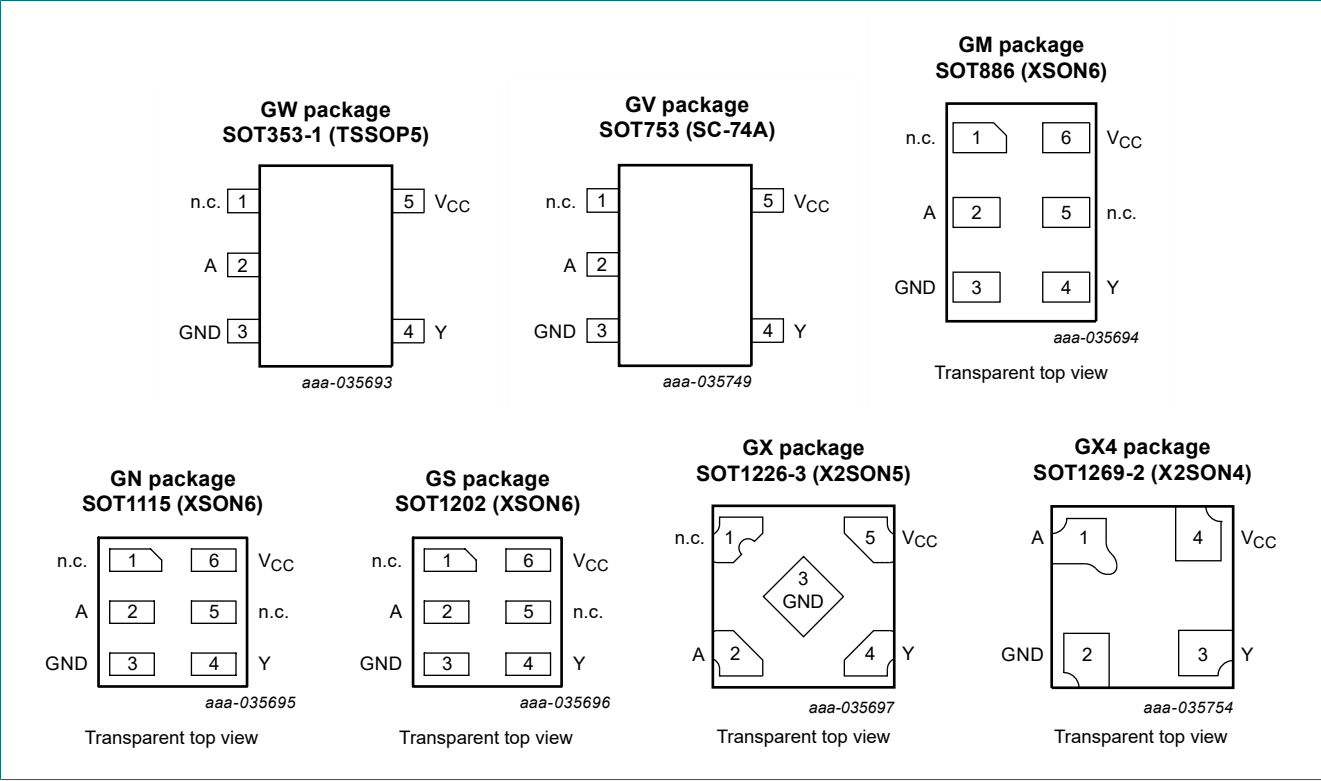


Fig. 3. Logic diagram

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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin			Description
	SC-74A, TSSOP5 and X2SON5	XSON6	X2SON4	
n.c.	1	1, 5	-	not connected
A	2	2	1	data input
GND	3	3	2	ground (0 V)
Y	4	4	3	data output
V _{CC}	5	6	4	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
A	Y
L	L
H	H

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
V _I	input voltage		-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
V _O	output voltage	Active mode and Power-down mode	-0.5	+4.6	V
I _O	output current	V _O = 0 V to V _{CC}	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C			
		SOT353-1 (TSSOP5) SOT753 (SC-74A) SOT886 (XSON6) SOT1115 (XSON6) SOT1202 (XSON6) SOT1226-3 (X2SON5)	-	250	mW
		SOT1269-2 (X2SON4)	-	150	mW

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.
For SOT753 (SC-74A) package: P_{tot} derates linearly with 3.8 mW/K above 85 °C.
For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.
For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.
For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.
For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.
- [3] For SOT1269-2 (X2SON4) package: P_{tot} derates linearly with 1.7 mW/K above 57 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
V _I	input voltage		0	3.6	V
V _O	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	µA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	µA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	µA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	40	µA
C _I	input capacitance	V _I = GND or V _{CC} ; V _{CC} = 0 V to 3.6 V	-	1.1	-	pF
C _O	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +85 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	µA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.5	µA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	µA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	50	µA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 µA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 µA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	µA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.75	µA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	µA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	1.4	µA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	75	µA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 pF										
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	19.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	5.7	10.6	2.5	10.9	2.5	11.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.2	6.5	2.3	7.1	2.3	7.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.6	5.5	1.9	6.1	1.9	6.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.0	4.2	1.8	4.6	1.8	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.7	3.6	1.5	3.8	1.5	4.0	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10 pF										
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	22.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.6	12.4	2.7	12.9	2.7	13.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.8	7.8	2.4	8.3	2.4	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.2	6.3	2.4	6.8	2.4	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.5	4.8	2.1	5.3	2.1	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.3	4.4	2.0	4.6	2.0	4.8	ns
C _L = 15 pF										
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	26.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.4	14.1	3.1	14.7	3.1	14.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.4	8.7	2.8	9.5	2.8	9.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	4.7	7.1	2.7	7.8	2.7	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	4.0	5.6	2.5	6.0	2.5	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.7	4.9	2.2	5.2	2.2	5.5	ns
C _L = 30 pF										
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	36.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	9.7	19.0	3.7	19.8	3.7	20.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	7.0	11.2	3.6	12.4	3.6	13.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.0	9.2	3.4	10.1	3.4	10.7	ns
		V _{CC} = 2.3 V to 2.7 V	3.4	5.1	7.0	3.2	7.5	3.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	4.8	6.2	3.1	7.1	3.1	7.5	ns
C _L = 5 pF, 10 pF, 15 pF and 30 pF										
C _{PD}	power dissipation capacitance	f = 1 MHz; V _I = GND to V _{CC} [3]								
		V _{CC} = 0.8 V	-	2.5	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.0	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11.1. Waveform and test circuit

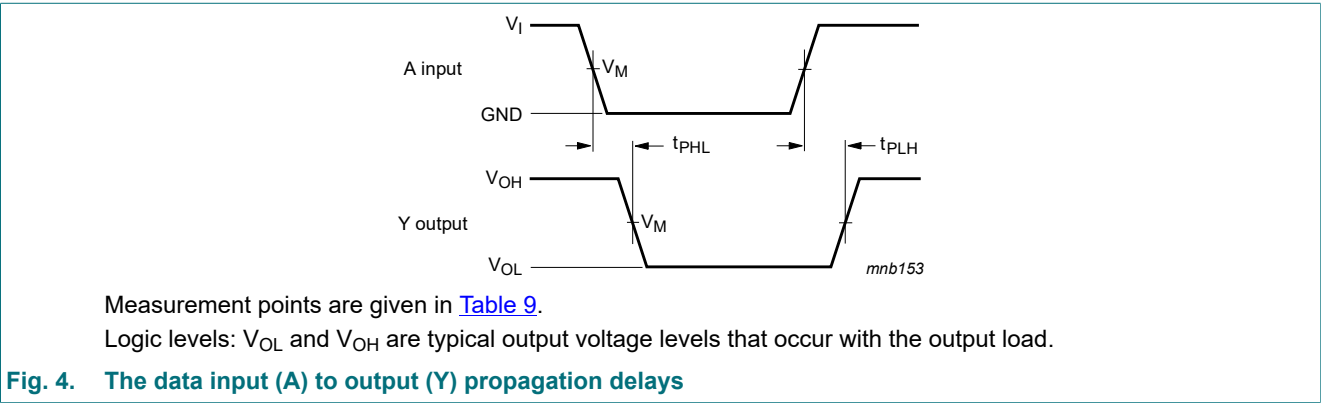


Table 9. Measurement points

Supply voltage	Input			Output
V_{CC}	V_M	V_I	$t_r = t_f$	V_M
0.8 V to 3.6 V	$0.5 \times V_{CC}$	V_{CC}	$\leq 3.0 \text{ ns}$	$0.5 \times V_{CC}$

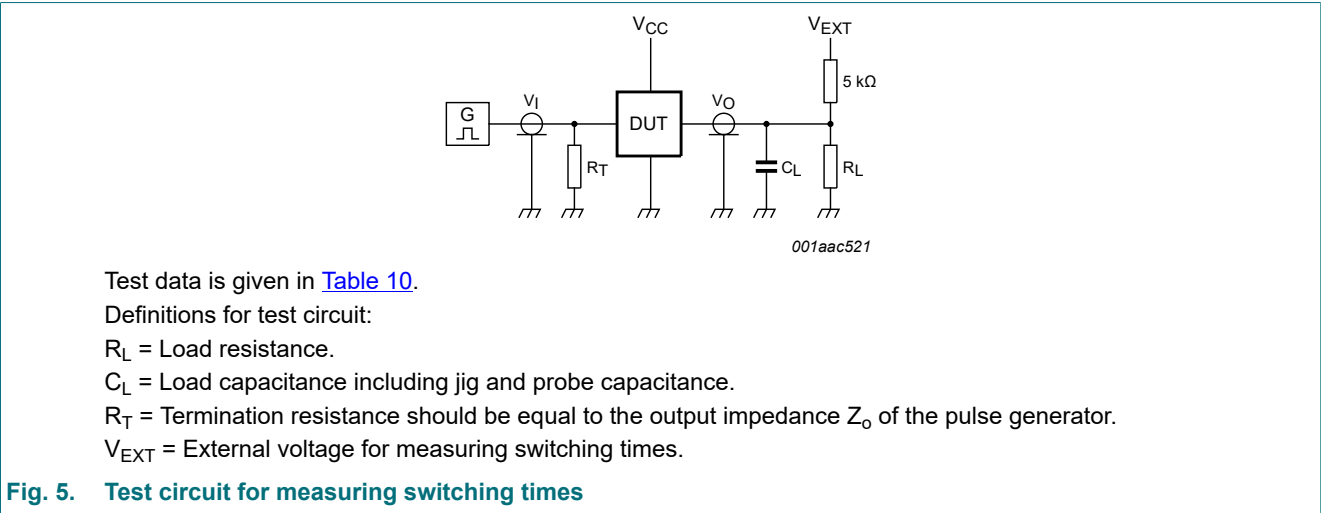


Table 10. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L [1]	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times, $R_L = 5 \text{ k}\Omega$.
 For measuring propagation delays, setup and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

12. Transfer characteristics

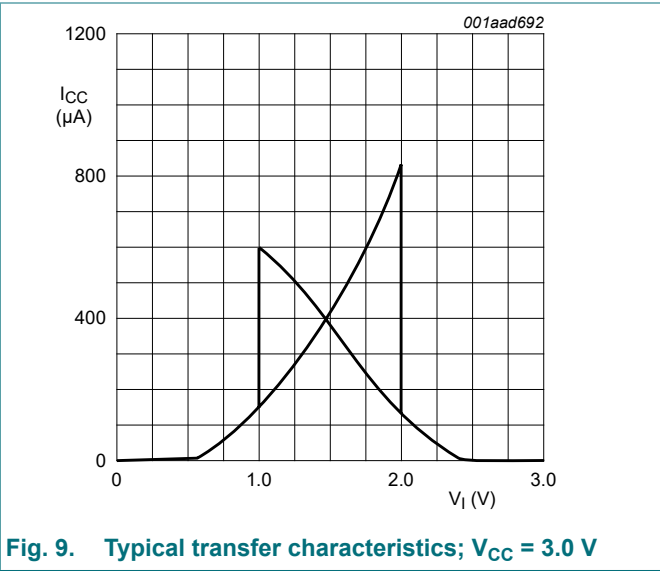
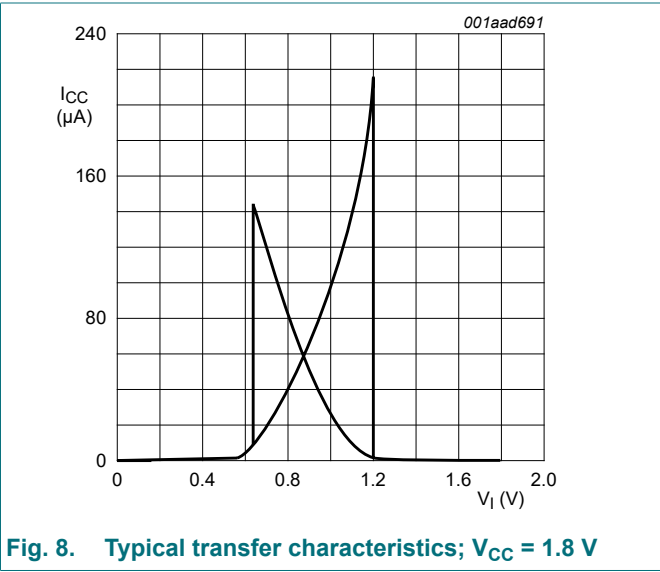
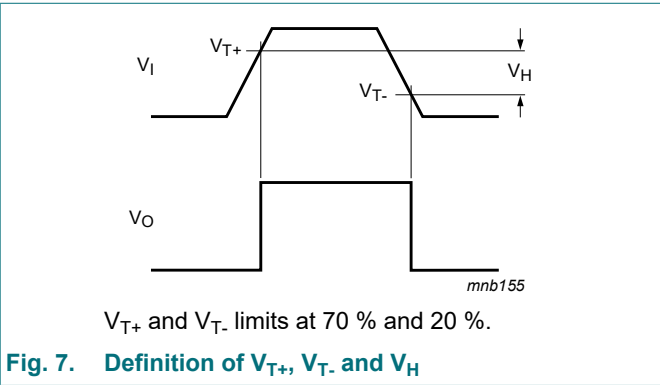
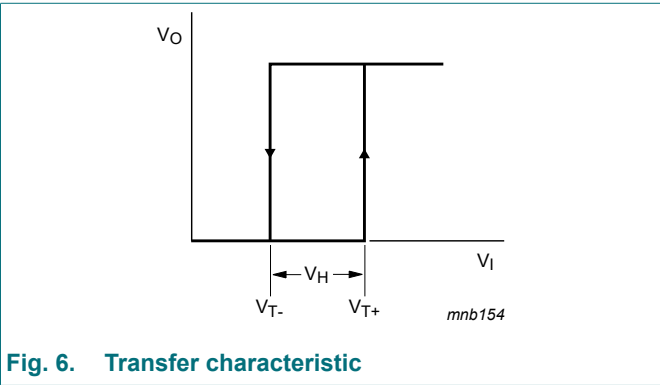
Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T _{amb} = 25 °C						
V _{T+}	positive-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.30	-	0.60	V
		V _{CC} = 1.1 V	0.53	-	0.90	V
		V _{CC} = 1.4 V	0.74	-	1.11	V
		V _{CC} = 1.65 V	0.91	-	1.29	V
		V _{CC} = 2.3 V	1.37	-	1.77	V
		V _{CC} = 3.0 V	1.88	-	2.29	V
V _{T-}	negative-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H	hysteresis voltage	see Fig. 6 , Fig. 7 , Fig. 8 and Fig. 9				
		V _{CC} = 0.8 V	0.07	-	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	V

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T _{amb} = -40 °C to +85 °C						
V _{T+}	positive-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.30	-	0.60	V
		V _{CC} = 1.1 V	0.53	-	0.90	V
		V _{CC} = 1.4 V	0.74	-	1.11	V
		V _{CC} = 1.65 V	0.91	-	1.29	V
		V _{CC} = 2.3 V	1.37	-	1.77	V
		V _{CC} = 3.0 V	1.88	-	2.29	V
V _{T-}	negative-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H	hysteresis voltage	see Fig. 6 , Fig. 7 , Fig. 8 and Fig. 9				
		V _{CC} = 0.8 V	0.07	-	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	V
T _{amb} = -40 °C to +125 °C						
V _{T+}	positive-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.30	-	0.62	V
		V _{CC} = 1.1 V	0.53	-	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.32	V
V _{T-}	negative-going threshold voltage	see Fig. 6 and Fig. 7				
		V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H	hysteresis voltage	see Fig. 6 , Fig. 7 , Fig. 8 and Fig. 9				
		V _{CC} = 0.8 V	0.07	-	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	V

12.1. Waveforms transfer characteristics



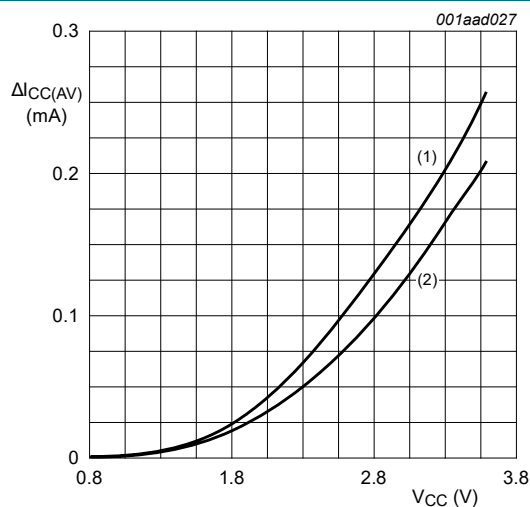
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$P_{ad} = f_i \times (t_r \times I_{CC(AV)} + t_f \times I_{CC(AV)}) \times V_{CC}$ where:

- P_{ad} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $I_{CC(AV)}$ = average additional supply current (μA).

Average I_{CC} differs with positive or negative input transitions, as shown in [Fig. 10](#).



(1) Positive-going edge.

(2) Negative-going edge.

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig. 10. Average I_{CC} as a function of V_{CC}

14. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm SOT353-1

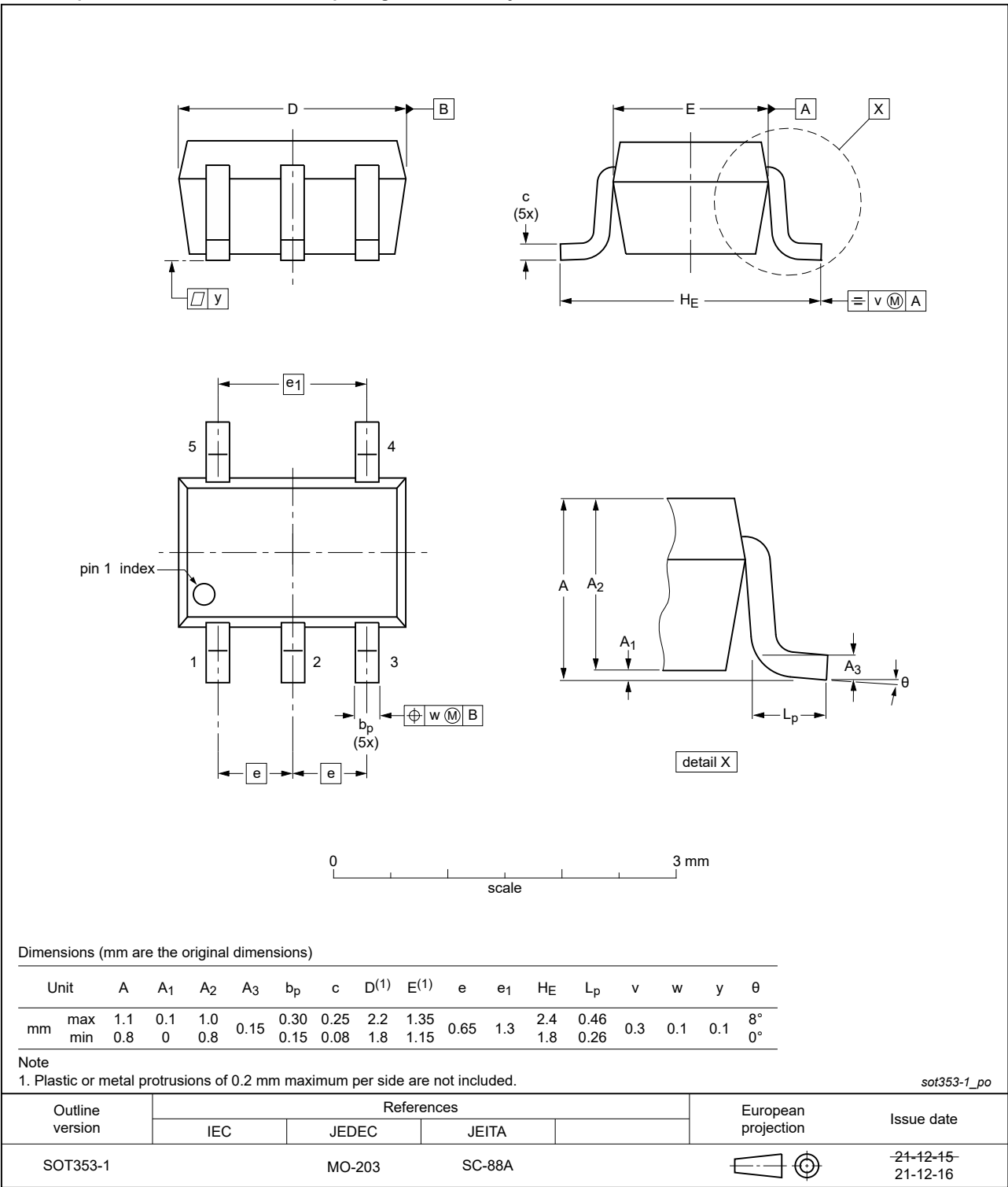


Fig. 11. Package outline SOT353-1 (TSSOP5)

Plastic surface-mounted package; 5 leads

SOT753

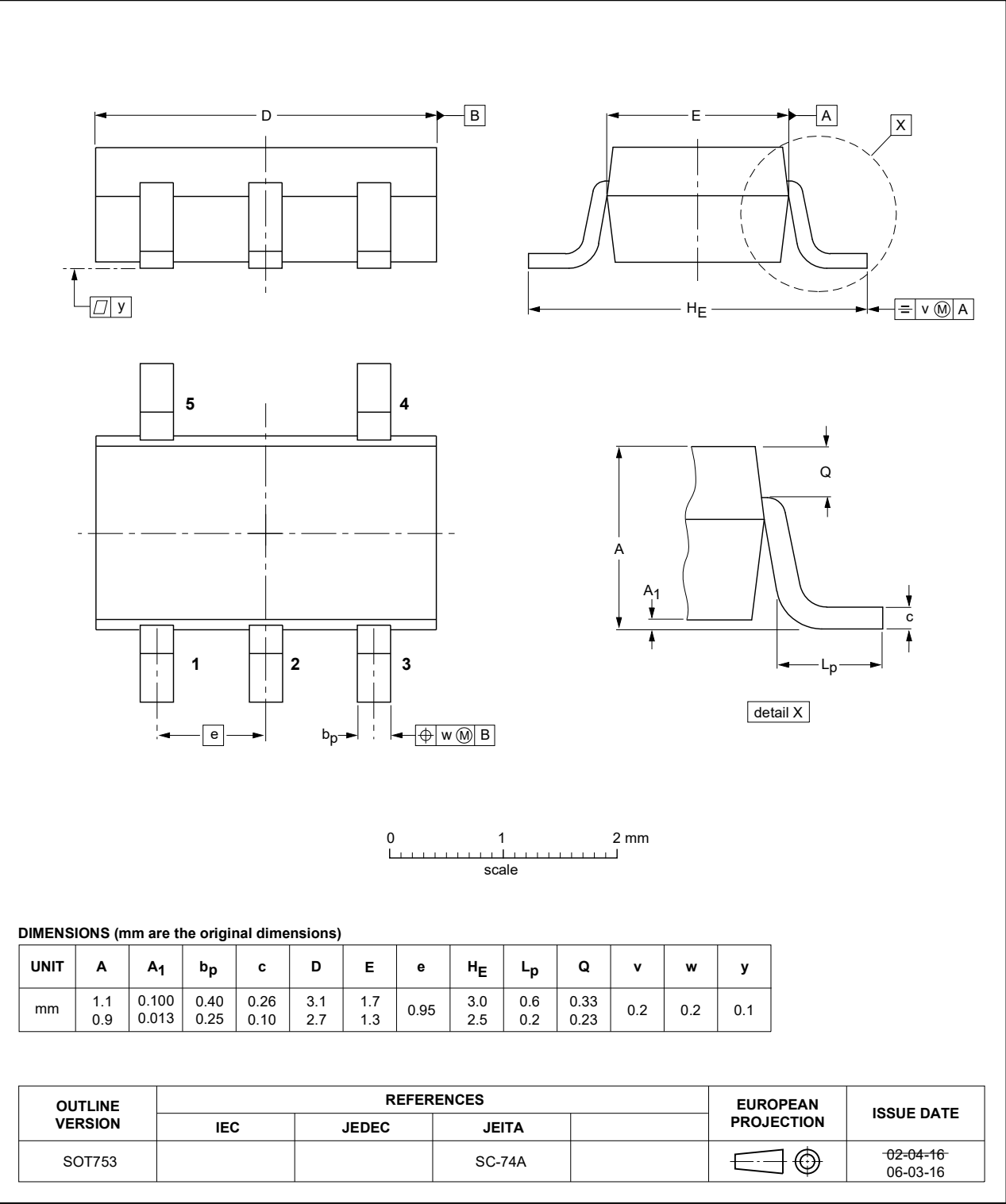


Fig. 12. Package outline SOT753 (SC-74A)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

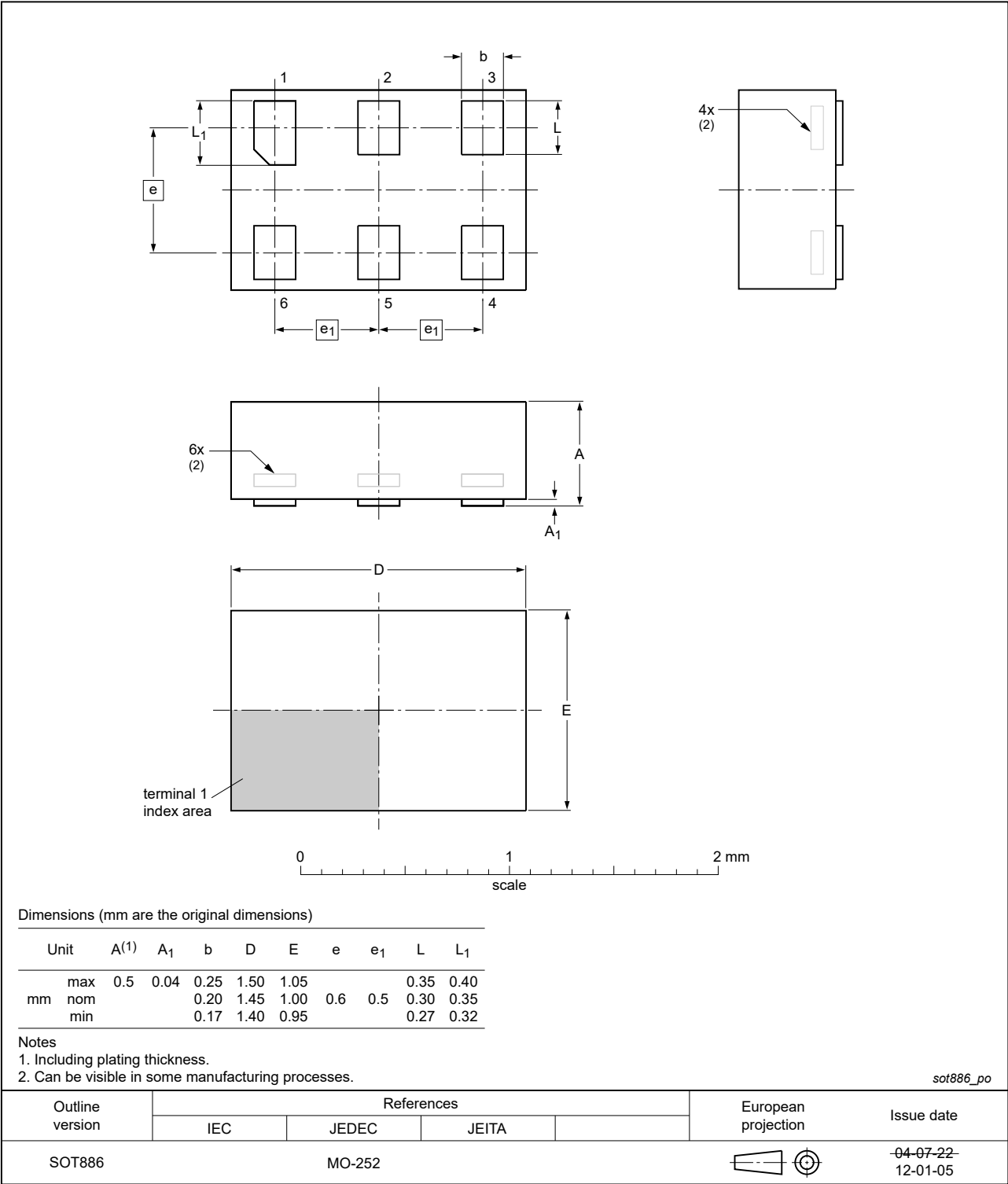


Fig. 13. Package outline SOT886 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115

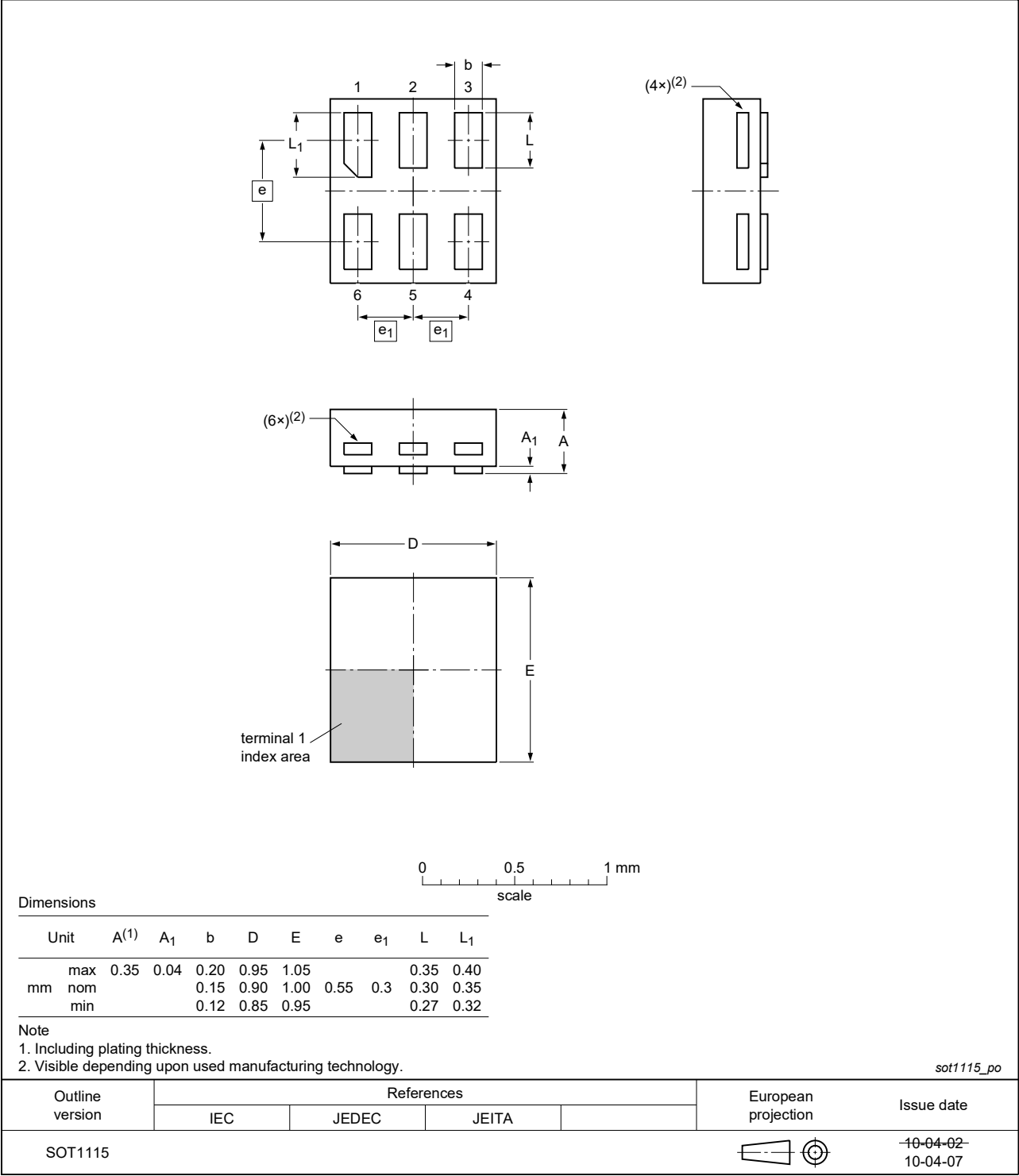
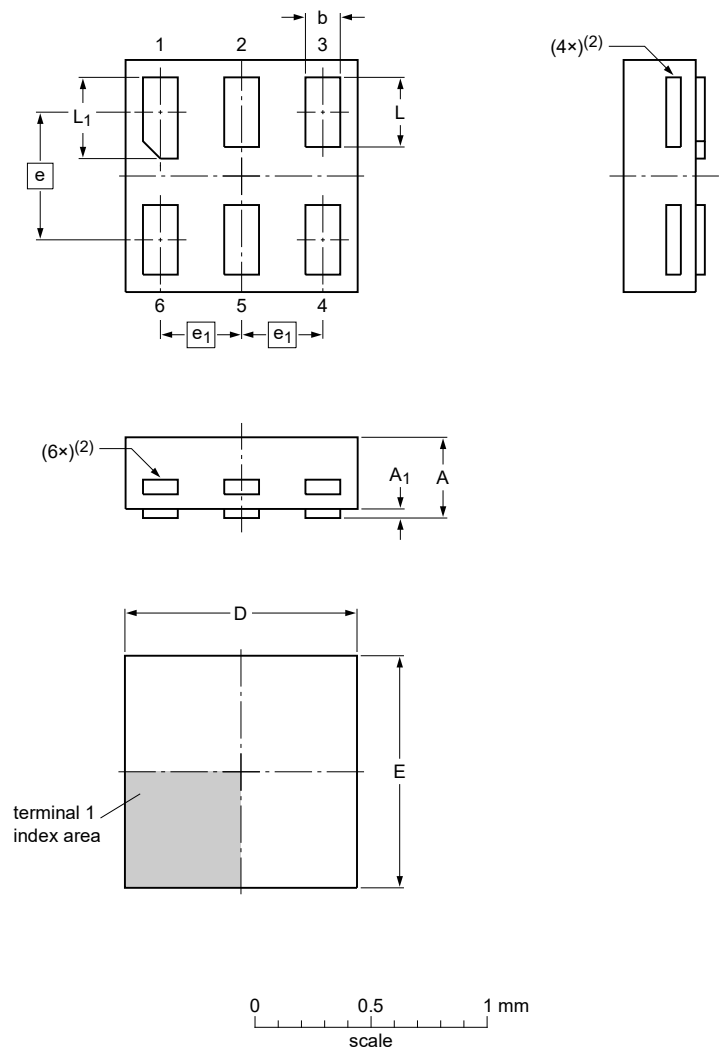


Fig. 14. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202



Dimensions

Unit	A ⁽¹⁾	A ₁	b	D	E	e	e ₁	L	L ₁
mm	max	0.35	0.04	0.20	1.05	1.05		0.35	0.40
	nom			0.15	1.00	1.00	0.55	0.30	0.35
	min			0.12	0.95	0.95		0.27	0.32

Note

- 1. Including plating thickness.
- 2. Visible depending upon used manufacturing technology.

sot1202_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1202						10-04-02 10-04-06

Fig. 15. Package outline SOT1202 (XSON6)

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;
5 terminals; body 0.8 x 0.8 x 0.32 mm

SOT1226-3

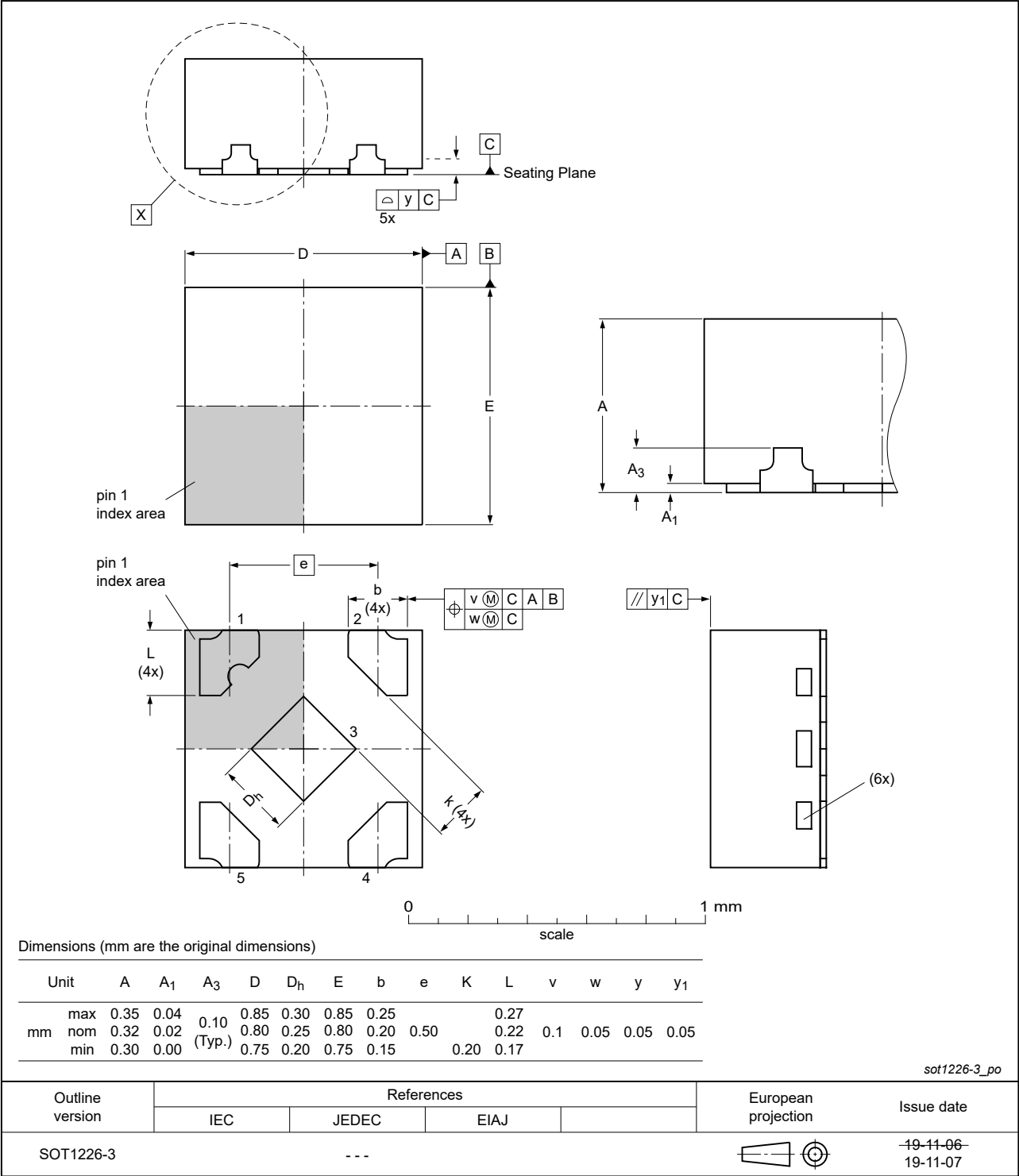


Fig. 16. Package outline SOT1226-3 (X2SON5)

X2SON4: plastic thermal enhanced extremely thin small outline package; no leads;
4 terminals; body 0.6 x 0.6 x 0.32 mm

SOT1269-2

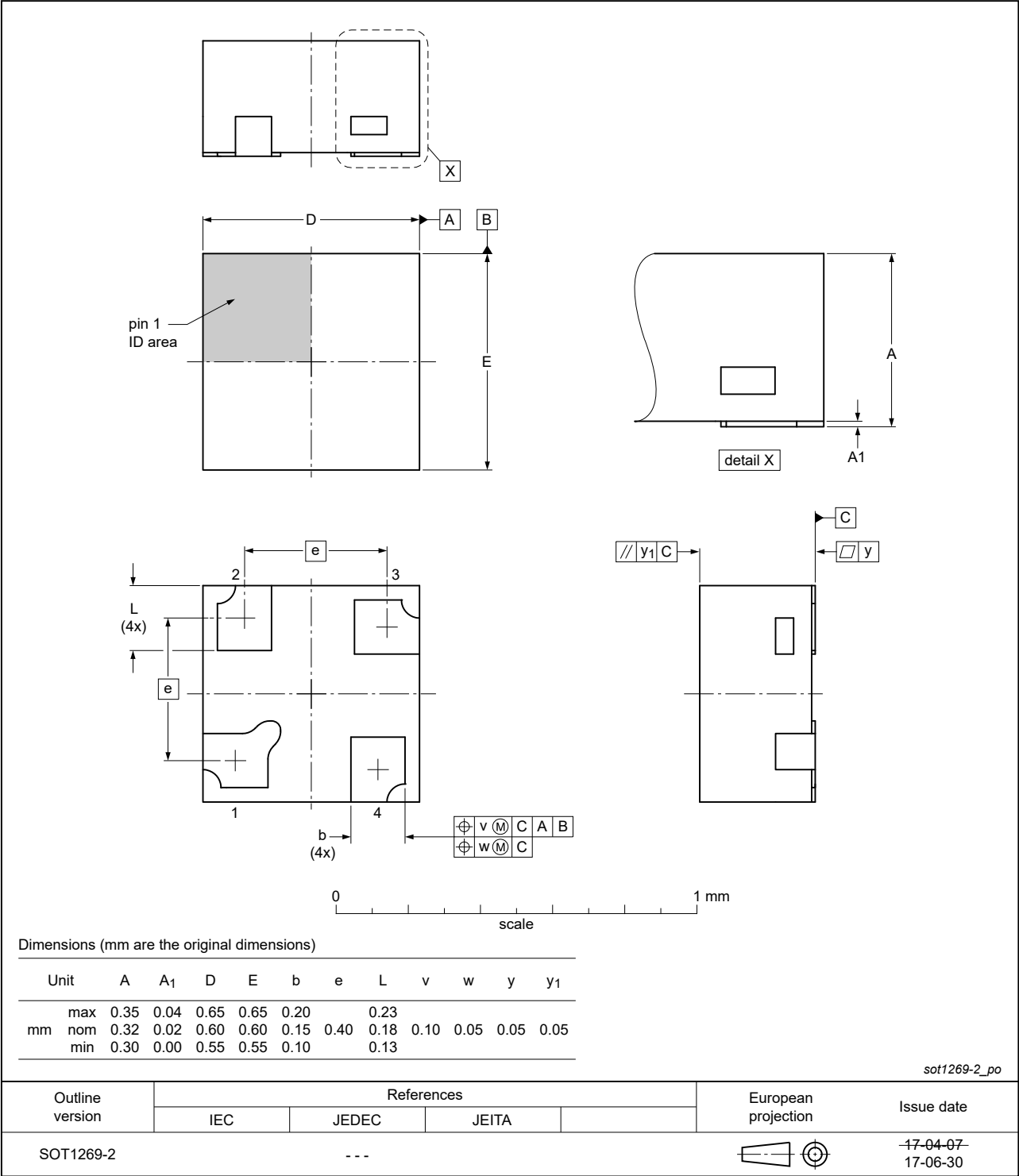


Fig. 17. Package outline SOT1269-2 (X2SON4)

15. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

16. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G17 v.14	20230713	Product data sheet	-	74AUP1G17 v.13
Modifications:	Section 2: ESD specification updated according to the latest JEDEC standard.			
74AUP1G17 v.13	20220113	Product data sheet	-	74AUP1G17 v.12
Modifications:	Fig. 11: Package outline drawing for SOT353-1 (TSSOP5) has changed.			
74AUP1G17 v.12	20210707	Product data sheet	-	74AUP1G17 v.11
Modifications:	- SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package. - Type number 74AUP1G17GF (SOT891/XSON6) removed. Table 5: Derating values for P_{tot} total power dissipation have been updated.			
74AUP1G17 v.11	20180608	Product data sheet	-	74AUP1G17 v.10
Modifications:	Added type number 74AUP1G17GX4 (SOT1269-2)			
74AUP1G17 v.10	20170519	Product data sheet	-	74AUP1G17 v.9
Modifications:	- The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. - Legal texts have been adapted to the new company name where appropriate.			
74AUP1G17 v.9	20161104	Product data sheet	-	74AUP1G17 v.8
Modifications:	Added type number 74AUP1G17GV (SOT753)			
74AUP1G17 v.8	20150115	Product data sheet	-	74AUP1G17 v.7
Modifications:	Marking code Table 2: typo corrected in type number 74AUP1G17GX.			
74AUP1G17 v.7	20120716	Product data sheet	-	74AUP1G17 v.6
Modifications:	Package outline drawing of SOT1226 (Fig. 16) modified.			
74AUP1G17 v.6	20120412	Product data sheet	-	74AUP1G17 v.5
Modifications:	- Added type number 74AUP1G17GX (SOT1226) - Package outline drawing of SOT886 (Fig. 13) modified.			
74AUP1G17 v.5	20111124	Product data sheet	-	74AUP1G17 v.4
Modifications:	Legal pages updated.			
74AUP1G17 v.4	20100715	Product data sheet	-	74AUP1G17 v.3
74AUP1G17 v.3	20090710	Product data sheet	-	74AUP1G17 v.2
74AUP1G17 v.2	20060727	Product data sheet	-	74AUP1G17 v.1
74AUP1G17 v.1	20050726	Product data sheet	-	-

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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